RGW40TK65

650V 20A Field Stop Trench IGBT

Datasheet

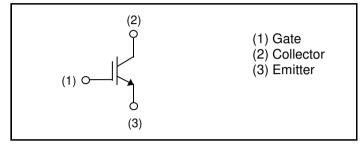
V _{CES}	650V
I _{C (100°C)}	16A
V _{CE(sat) (Typ.)}	1.5V
P_{D}	61W

Outline TO-3PFM

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

●Inner Circuit



Application

PFC

UPS

Welding

Solar Inverter

ΙH

●Packaging Specifications

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Packaging	Tube				
Reel Size (mm)	-				
Tape Width (mm)	-				
Basic Ordering Unit (pcs)	450				
Packing Code	C11				
Marking	RGW40TK65				
	Packaging Reel Size (mm) Tape Width (mm) Basic Ordering Unit (pcs) Packing Code				

● **Absolute Maximum Ratings** (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	±30	V
Collector Current	T _C = 25°C	I _C	27	Α
	T _C = 100°C	I _C	16	Α
Pulsed Collector Current	I _{CP} *1	80	Α	
Power Dissipation	T _C = 25°C	P _D	61	W
	T _C = 100°C	P _D	30	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax.}

●Thermal Resistance

Parameter	Symbol	Values			Unit
Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	ı	2.44	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
Tarameter Symbol Conditions	Min.	Тур.	Max.			
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	ı	ı	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	-	ı	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V$, $V_{CE} = 0V$	1	1	±200	nA
Gate - Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$V_{CE} = 5V, I_{C} = 13.3mA$	5.0	6.0	7.0	٧
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 20A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.5 1.85	1.9 -	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Doromator	Symbol	Conditions	Values			1.1-24
Parameter			Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	$V_{CE} = 30V$,	-	1680	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$,	-	47	-	рF
Reverse transfer Capacitance	C_{res}	f = 1MHz	-	31	-	
Total Gate Charge	Q_g	V _{CE} = 400V,	-	59	-	
Gate - Emitter Charge	Q_ge	I _C = 20A,	_	13	-	nC
Gate - Collector Charge	Q_{gc}	$V_{GE} = 15V$	-	23	-	
Turn - on Delay Time	t _{d(on)}		-	33	-	ns mJ
Rise Time	t _r	$I_C = 20A, V_{CC} = 400V,$ $V_{GF} = 15V, R_G = 10\Omega,$	_	10	-	
Turn - off Delay Time	$t_{d(off)}$	$T_i = 25^{\circ}C$	_	76	1	
Fall Time	t _f	Inductive Load	_	63	ı	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	_	0.33	1	
Turn - off Switching Loss	E _{off}		-	0.30	1	
Turn - on Delay Time	t _{d(on)}		_	31	-	
Rise Time	t _r	$I_{C} = 20A, V_{CC} = 400V,$ $V_{GE} = 15V, R_{G} = 10\Omega,$	_	10	1	ns
Turn - off Delay Time	$t_{d(off)}$	$T_i = 175^{\circ}C$	_	102	-	
Fall Time	t _f	Inductive Load *E _{on} include diode reverse recovery	-	76	-	
Turn - on Switching Loss	E _{on}		-	0.34	-	mJ
Turn - off Switching Loss	E _{off}		-	0.43	1	1110
Reverse Bias Safe Operating	RBSOA	$I_C = 80A$, $V_{CC} = 520V$, $V_P = 650V$, $V_{GE} = 15V$,	FULL SQUARE			-
Area		$R_G = 100\Omega, T_j = 175^{\circ}C$				

Electrical Characteristic Curves

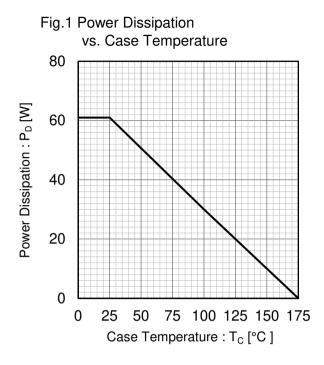


Fig.2 Collector Current vs. Case Temperature 40Vs. Case Temperature 4

Fig.3 Forward Bias Safe Operating Area

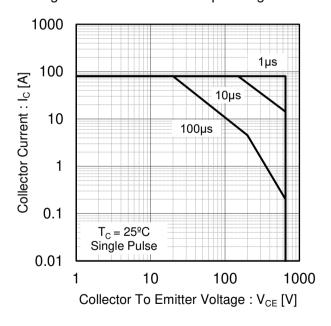
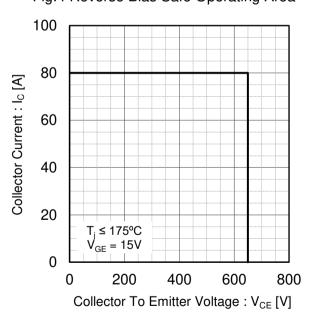


Fig.4 Reverse Bias Safe Operating Area



Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

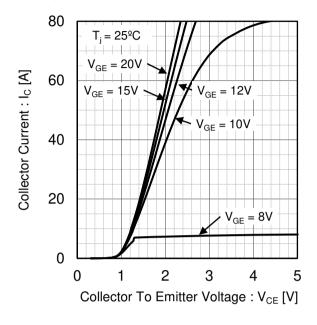


Fig.6 Typical Output Characteristics

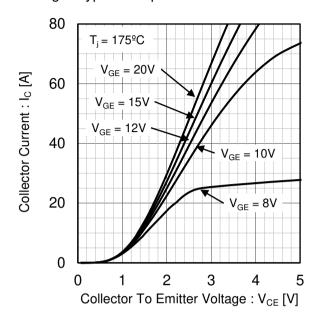


Fig.7 Typical Transfer Characteristics

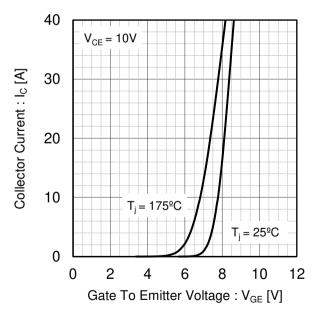
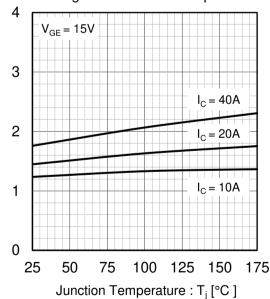


Fig.8 Typical Collector to Emitter Saturation Voltage vs. Junction Temperature



Collector To Emitter Saturation

Voltage: V_{CE(sat)} [V]

5

Electrical Characteristic Curves

10

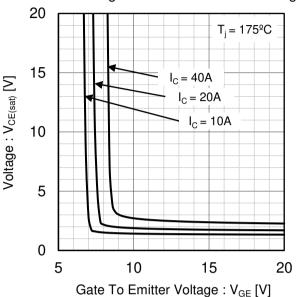
Fig.11 Typical Switching Time

15

Gate To Emitter Voltage: VGE [V]

Fig.9 Typical Collector to Emitter Saturation

Fig.10 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage



20

Collecter Current : I_C [A]

30

40

Fig.12 Typical Switching Time vs. Gate Resistance 1000 Switching Time [ns] $t_{d(off)}$ 100 $t_{d(on)}$ 10 V_{CC} = 400V, V_{GE} = 15V, I_C = 20A, T_j = 175 $^{\circ}$ C Inductive load 1 0 10 20 30 40 50 Gate Resistance : $R_G[\Omega]$

1

0

10

Collector To Emitter Saturation

20

Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current 10

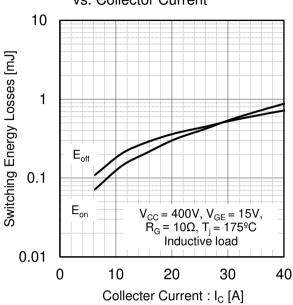


Fig.14 Typocal Switching Energy Losses vs. Gate Resistance

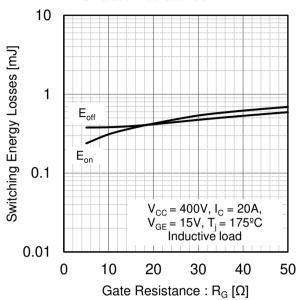


Fig.15 Typical Capacitance vs. Collector to Emitter Voltage

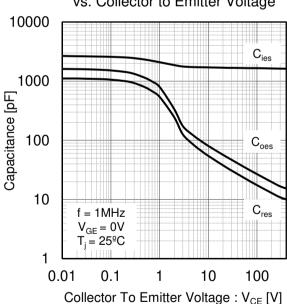
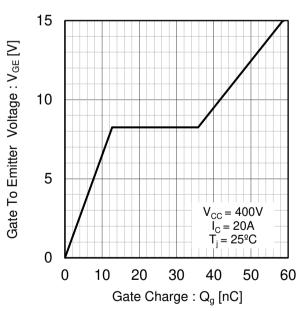
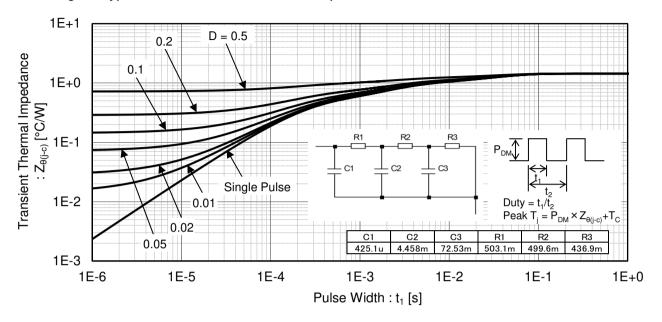


Fig.16 Typical Gate Charge



• Electrical Characteristic Curves

Fig.17 Typical IGBT Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform

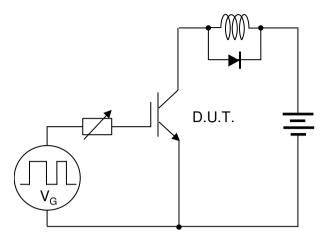


Fig.18 Inductive Load Circuit

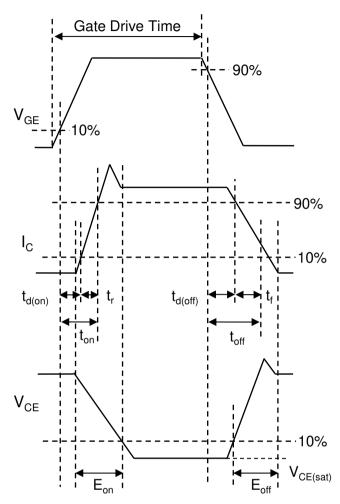


Fig.19 Inductive Load Waveform

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